

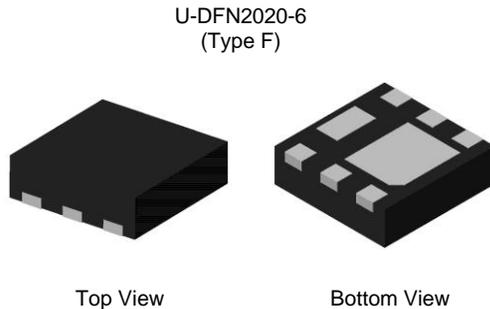
Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C |
|-------------------|--------------------------------|--|
| -20V | 27mΩ @ V _{GS} = -4.5V | -7.6A |
| | 32mΩ @ V _{GS} = -2.5V | -6.7A |
| | 50mΩ @ V _{GS} = -1.8V | -5.2A |
| | 90mΩ @ V _{GS} = -1.5V | -3.9A |

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Battery management applications
- Power management functions
- DC-DC converters

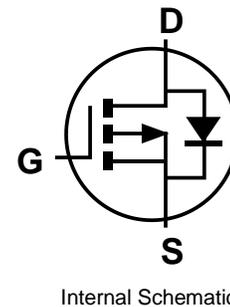
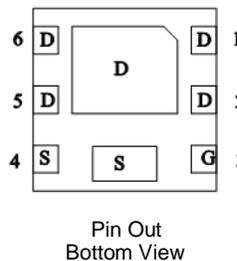


Features

- 0.6mm Profile – Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. “Green” Device (Note 3)**
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/contact-us) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

Mechanical Data

- Package: U-DFN2020-6
- Package Material: Molded Plastic, “Green” Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 **e4**
- Weight: 0.007 grams (Approximate)



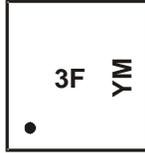
Ordering Information (Note 4)

| Part Number | Package | Marking | Reel Size (inches) | Packing | |
|----------------|----------------------|---------|--------------------|---------|---------|
| | | | | Qty. | Carrier |
| DMP2023UFDF-7 | U-DFN2020-6 (Type F) | 3F | 7 | 3,000 | Reel |
| DMP2023UFDF-13 | U-DFN2020-6 (Type F) | 3F | 13 | 10,000 | Reel |

- Notes:
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

Site 1

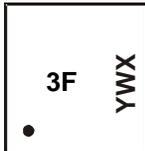


3F = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: J = 2022)
 M = Month (ex: 9 = September)

Date Code Key

| Year | 2014 | | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 |
|-------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code | B | | J | K | L | M | N | O | P | R | S | T |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Site 2



3F = Product Type Marking Code
 YWX = Date Code Marking
 Y = Year (ex: 2 = 2022)
 W = Week (ex: a = Week 27; z Represents Week 52 and 53)
 X = Internal Code (ex: U = Monday)

Date Code Key

| Year | 2014 | ... | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 |
|---------------|------|-----|------|-------|------|------|------|------|------|------|------|------|
| Code | 4 | ... | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | 1 |
| Week | 1-26 | | | 27-52 | | | | 53 | | | | |
| Code | A-Z | | | a-z | | | | z | | | | |
| Internal Code | Sun | Mon | Tue | Wed | Thu | Fri | Sat | | | | | |
| Code | T | U | V | W | X | Y | Z | | | | | |

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|---|--------------|--|------------------|--------------|------|
| Drain-Source Voltage | | | V _{DSS} | -20 | V |
| Gate-Source Voltage | | | V _{GSS} | ±8 | V |
| Continuous Drain Current (Note 5) V _{GS} = -4.5V | Steady State | T _A = +25°C T _A = +70°C | I _D | -7.6 -6.1 | A |
| | t < 5s | T _A = +25°C T _A = +70°C | I _D | -9.5 -7.6 | A |
| Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%) | | | I _{DM} | -40 | A |
| Continuous Source-Drain Diode Current | | | I _S | -2 | A |
| Avalanche Current (Note 6) L = 0.1mH | | | I _{AS} | -23 | A |
| Avalanche Energy (Note 6) L = 0.1mH | | | E _{AS} | 27 | mJ |

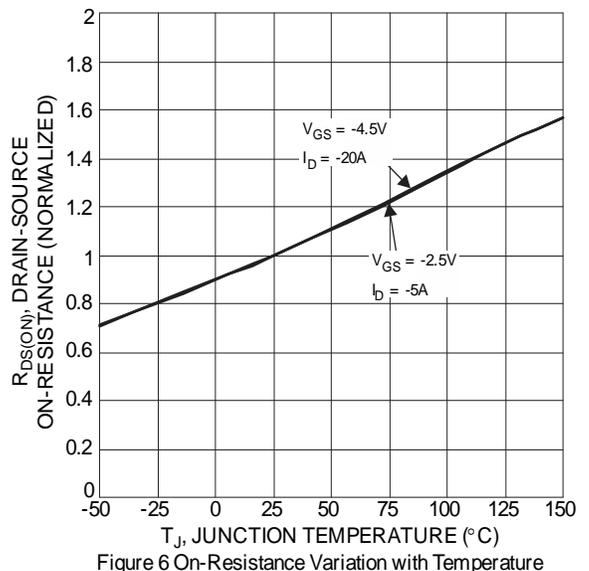
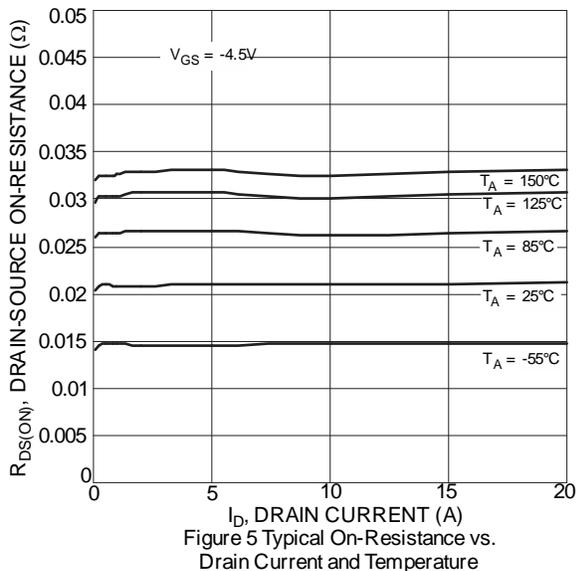
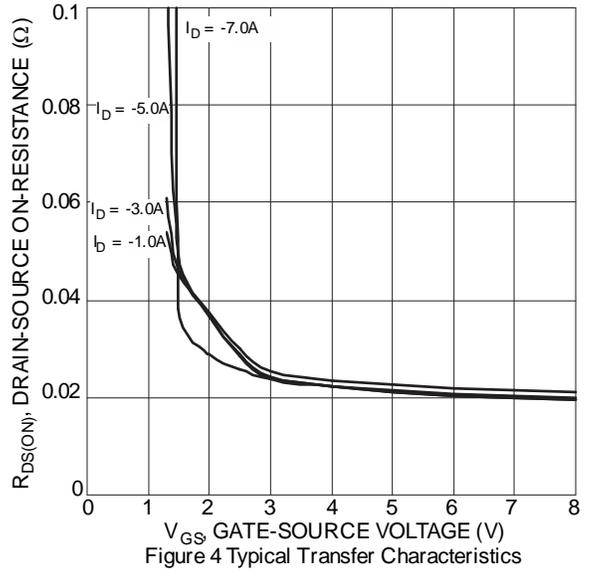
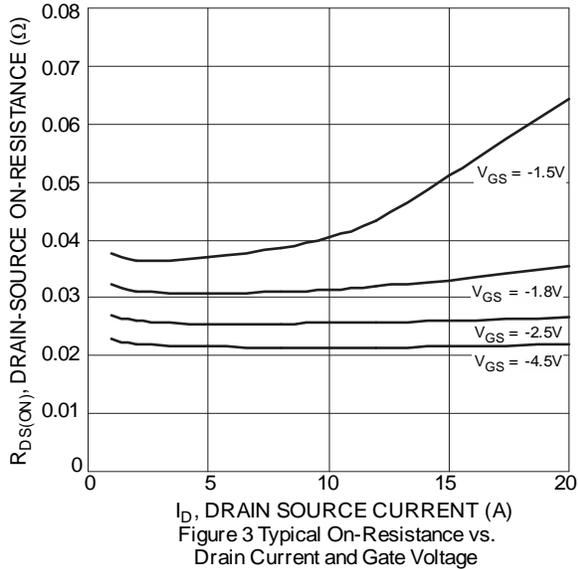
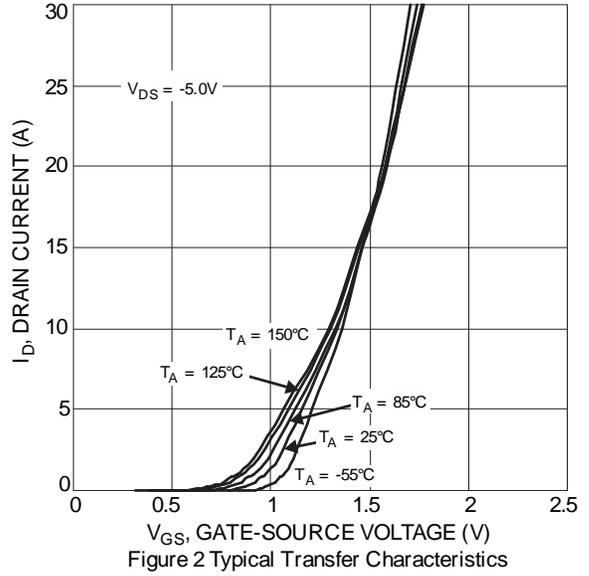
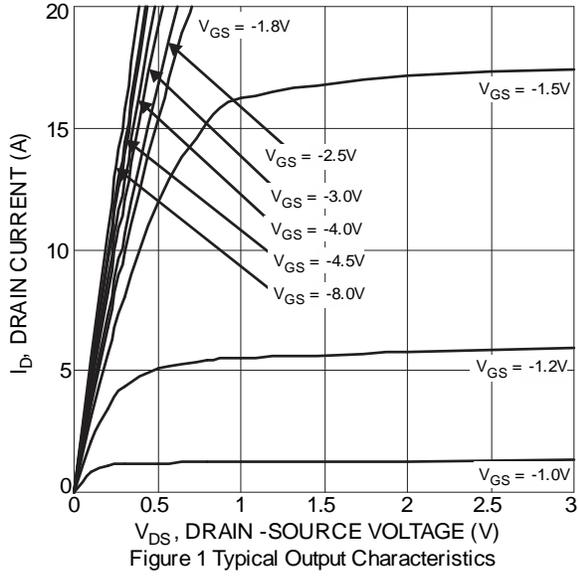
Thermal Characteristics

| Characteristic | | Symbol | Value | Unit |
|--|------------------------|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 7) | T _A = +25°C | P _D | 0.73 | W |
| | T _A = +70°C | | 0.47 | |
| Thermal Resistance, Junction to Ambient (Note 7) | Steady State | R _{θJA} | 171 | °C/W |
| | t < 5s | | 112 | |
| Total Power Dissipation (Note 5) | T _A = +25°C | P _D | 2.03 | W |
| | T _A = +70°C | | 1.30 | |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | R _{θJA} | 62 | °C/W |
| | t < 5s | | 40 | |
| Thermal Resistance, Junction to Case (Note 5) | Steady State | R _{θJC} | 9.3 | |
| Operating and Storage Temperature Range | | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|---------------------|------|-------|------|------|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | — | — | V | V _{GS} = 0V, I _D = -250μA |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | — | — | -1 | μA | V _{DS} = -20V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | — | — | ±100 | nA | V _{GS} = ±5V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 8) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.4 | — | -1.0 | V | V _{DS} = V _{GS} , I _D = -250μA |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | — | 27 | mΩ | V _{GS} = -4.5V, I _D = -7.0A |
| | | | — | 32 | | V _{GS} = -2.5V, I _D = -5.0A |
| | | | — | 50 | | V _{GS} = -1.8V, I _D = -3.0A |
| | | | — | 90 | | V _{GS} = -1.5V, I _D = -1.0A |
| Diode Forward Voltage | V _{SD} | — | -0.8 | -1.2 | V | V _{GS} = 0V, I _S = -1.0A |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | |
| Input Capacitance | C _{iss} | — | 1837 | — | pF | V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz |
| Output Capacitance | C _{oss} | — | 131 | — | | |
| Reverse Transfer Capacitance | C _{rss} | — | 115 | — | | |
| Gate Resistance | R _g | — | 14.8 | — | Ω | V _{DS} = 0V, V _{GS} = 0V, f = 1MHz |
| Total Gate Charge (V _{GS} = -4.5V) | Q _g | — | 27 | — | nC | V _{DS} = -15V, V _{GS} = -4.5V I _D = -4.0A |
| Gate-Source Charge | Q _{gs} | — | 2.8 | — | | |
| Gate-Drain Charge | Q _{gd} | — | 3.1 | — | | |
| Turn-On Delay Time | t _{D(ON)} | — | 5.8 | — | ns | V _{DS} = -15V, V _{GS} = -4.5V R _G = 1Ω, I _D = -4.0A |
| Turn-On Rise Time | t _R | — | 19.3 | — | | |
| Turn-Off Delay Time | t _{D(OFF)} | — | 168.5 | — | | |
| Turn-Off Fall Time | t _F | — | 77.3 | — | | |
| Reverse Recovery Time | t _{RR} | — | 46.5 | — | ns | I _F = -1.0A, dI/dt = 100A/μs |
| Reverse Recovery Charge | Q _{RR} | — | 33.8 | — | nC | I _F = -1.0A, dI/dt = 100A/μs |

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 - I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
 - Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to product testing.



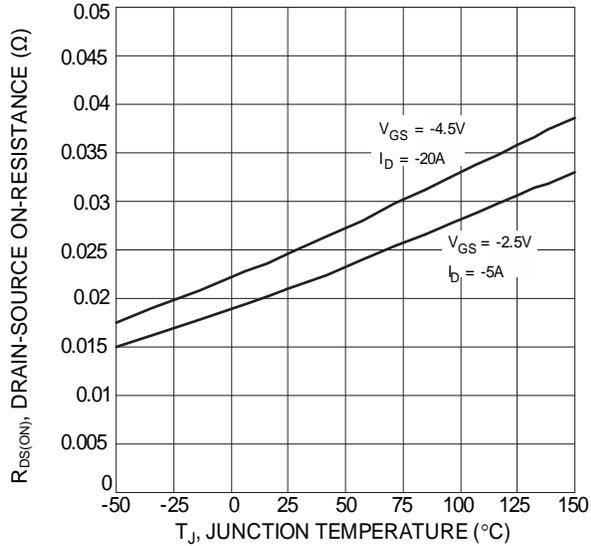


Figure 7 On-Resistance Variation with Temperature

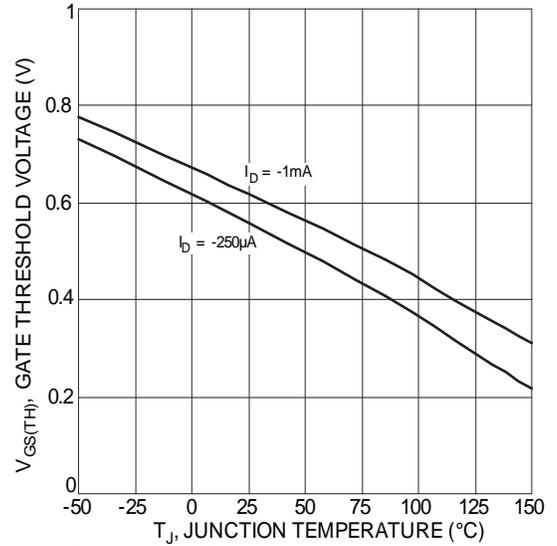


Figure 8 Gate Threshold vs. Junction Temperature

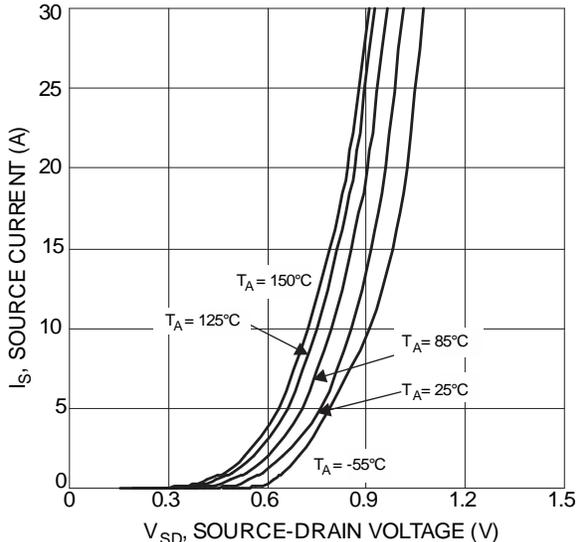


Figure 9 Diode Forward Voltage vs. Current

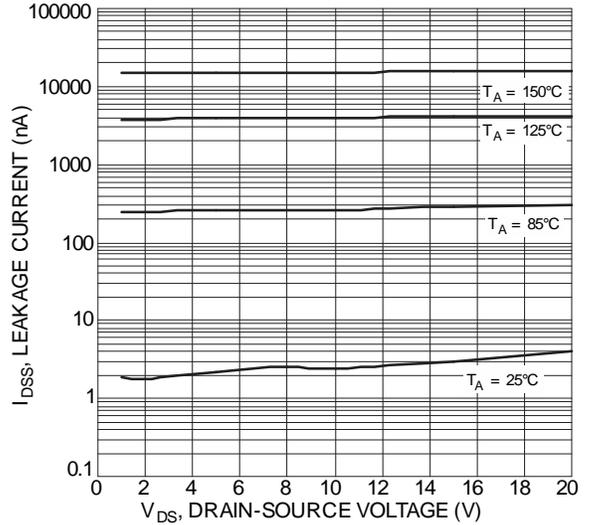


Figure 10 Typical Drain-Source Leakage Current vs. Voltage

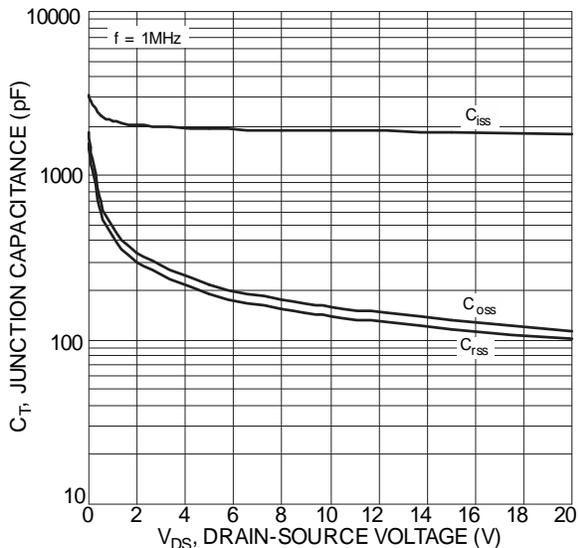


Figure 11 Typical Junction Capacitance

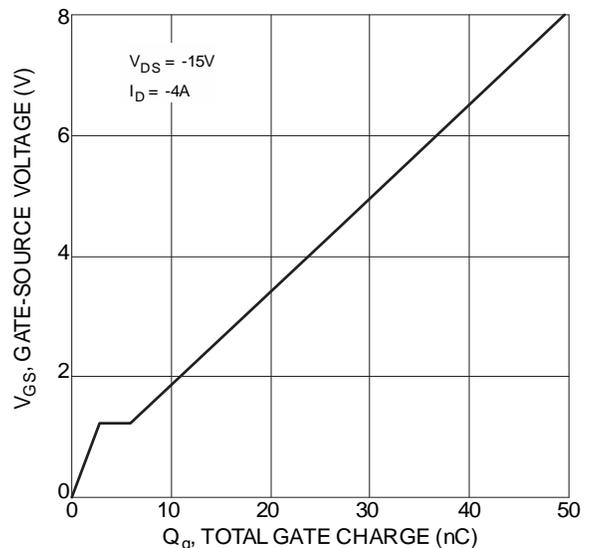
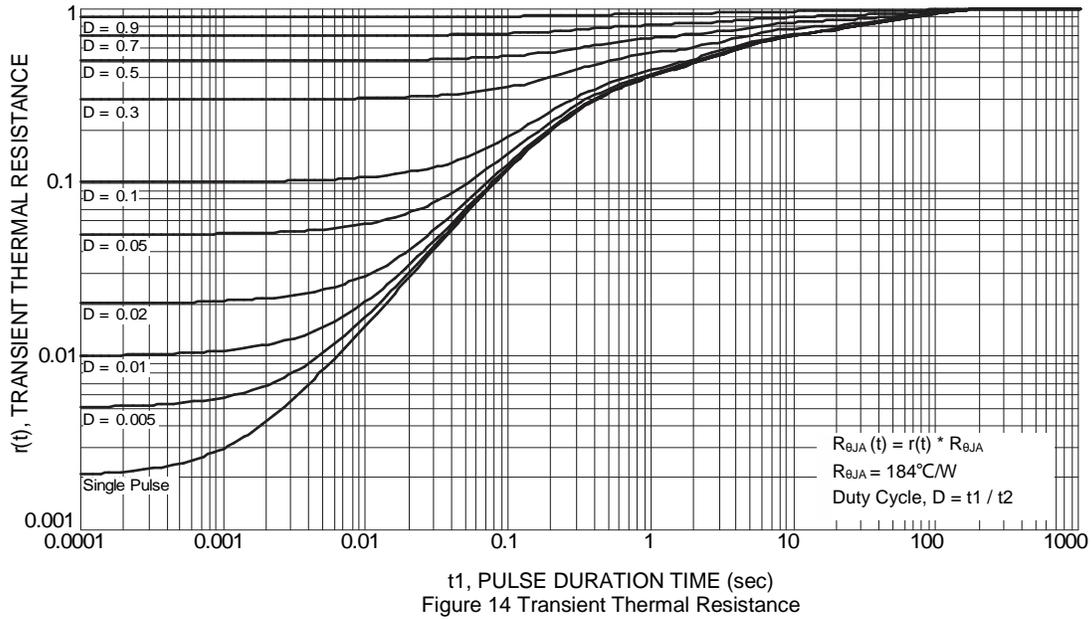
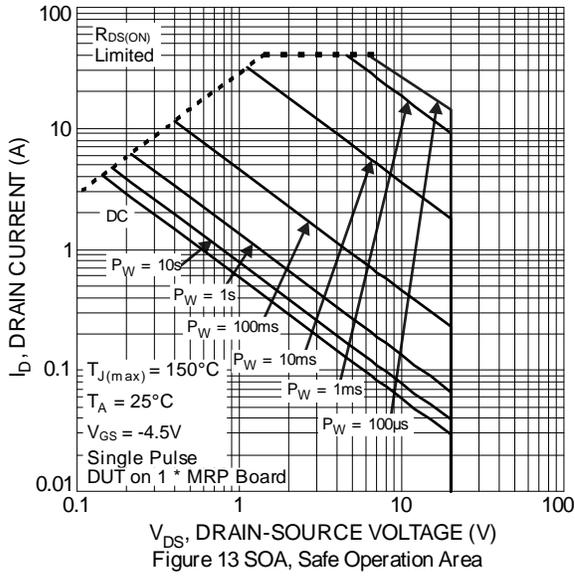


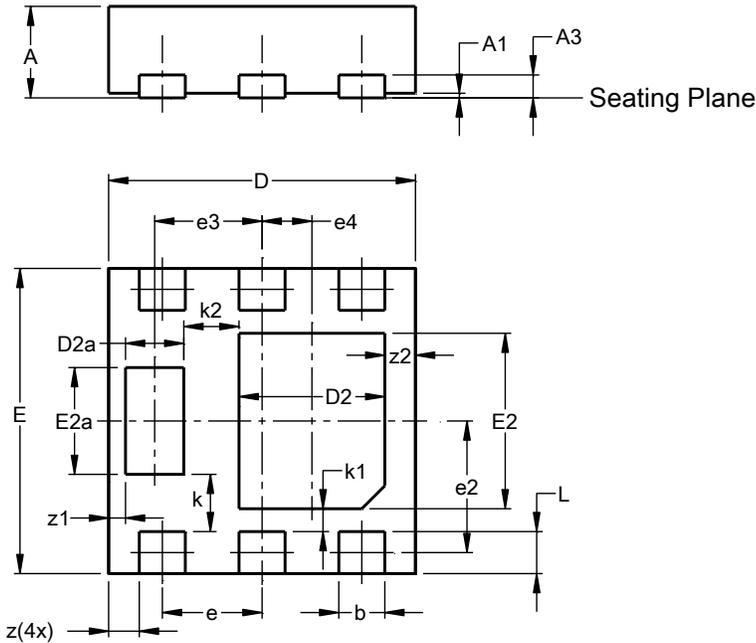
Figure 12 Gate-Charge Characteristics



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN2020-6 (Type F)

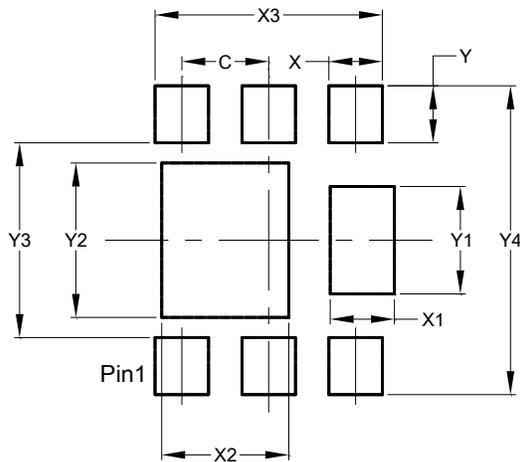


| U-DFN2020-6 (Type F) | | | |
|-------------------------|-----------|-------|-------|
| Dim | Min | Max | Typ |
| A | 0.57 | 0.63 | 0.60 |
| A1 | 0.00 | 0.05 | 0.03 |
| A3 | - | - | 0.15 |
| b | 0.25 | 0.35 | 0.30 |
| D | 1.95 | 2.05 | 2.00 |
| D2 | 0.85 | 1.05 | 0.95 |
| D2a | 0.33 | 0.43 | 0.38 |
| E | 1.95 | 2.05 | 2.00 |
| E2 | 1.05 | 1.25 | 1.15 |
| E2a | 0.65 | 0.75 | 0.70 |
| e | 0.65 BSC | | |
| e2 | 0.863 BSC | | |
| e3 | 0.70 BSC | | |
| e4 | 0.325 BSC | | |
| k | 0.37 BSC | | |
| k1 | 0.15 BSC | | |
| k2 | 0.36 BSC | | |
| L | 0.225 | 0.325 | 0.275 |
| z | 0.20 BSC | | |
| z1 | 0.110 BSC | | |
| z2 | 0.20 BSC | | |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN2020-6 (Type F)



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.650 |
| X | 0.400 |
| X1 | 0.480 |
| X2 | 0.950 |
| X3 | 1.700 |
| Y | 0.425 |
| Y1 | 0.800 |
| Y2 | 1.150 |
| Y3 | 1.450 |
| Y4 | 2.300 |

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